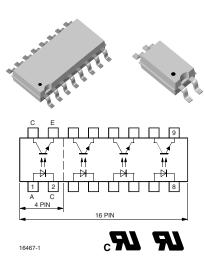
Vishay Semiconductors



Optocoupler, Phototransistor Output, Single/Quad Channel, Half Pitch Mini-Flat Package



DESCRIPTION

The TCMT1100 series consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in an 4-pin (single channel) up to 16-pin (quad channel) package.

The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

FEATURES

- Low profile package (half pitch)
- AC isolation test voltage 3750 V_{RMS}
- Low coupling capacitance of typical 0.3 pF
- Current Transfer Ratio (CTR) selected into groups



- · Low temperature coefficient of CTR
- Wide ambient temperature range
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

AGENCY APPROVALS

- UL1577, file no. E76222 system code M, double protection
- · C-UL CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-2 (VDE 0884)
 DIN EN 60747-5-5 pending

APPLICATIONS

- · Programmable logic controllers
- Modems
- · Answering machines
- · General applications

ORDER INFORMATION	
PART	REMARKS
TCMT1100	CTR 50 to 600 %, SOP-4
TCMT1102	CTR 63 to 125 %, SOP-4
TCMT1103	CTR 100 to 200 %, SOP-4
TCMT1104	CTR 160 to 320 %, SOP-4
TCMT1105	CTR 50 to 150 %, SOP-4
TCMT1106	CTR 100 to 300 %, SOP-4
TCMT1107	CTR 80 to 160 %, SOP-4
TCMT1108	CTR 130 to 260 %, SOP-4
TCMT1109	CTR 200 to 400 %, SOP-4
TCMT4100	CTR 50 to 600 %, quad channel, SOP-16
TCMT4106	CTR 100 to 300 %, quad channel, SOP-16





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ABSOLUTE MAXIMUM RATINGS (1)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V _R	6	V			
Forward current		I _F	60	mA			
Forward surge current	t _P ≤ 10 μs	I _{FSM}	1.5	Α			
Power dissipation		P _{diss}	100	mW			
Junction temperature		Tj	125	°C			
OUTPUT							
Collector emitter voltage		V_{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	50	mA			
Collector peak current	$t_P/T = 0.5, t_P \le 10 \text{ ms}$	I _{CM}	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		T _j	125	°C			
COUPLER							
AC isolation test voltage (RMS)	Related to standard climate 23/50 DIN 50014	V_{ISO}	3750	V _{RMS}			
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 100	°C			
Soldering temperature (2)		T _{sld}	260	°C			

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽²⁾ Refer to reflow profile soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTICS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I _F = 50 mA	V _F		1.25	1.6	V		
Junction capacitance	V _R = 0, f = 1 MHz	Cj		50		pF		
OUTPUT								
Collector emitter voltage	$I_{C} = 100 \ \mu A$	V_{CEO}	70			V		
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V		
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I _{CEO}			100	nA		
COUPLER								
Collector emitter saturation voltage	I _F = 10 mA, I _C = 1 mA	V _{CEsat}			0.3	V		
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c		100		kHz		
Coupling capacitance	f = 1 MHz	C _k		0.3		pF		

Note

 T_{amb} = 25 °C, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

 $^{^{(1)}}$ T_{amb} = 25 °C, unless otherwise specified.



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CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	TCMT1100	CTR	50		600	%
		TCMT1102	CTR	63		125	%
	$V_{CE} = 5 \text{ V}, I_{F} = 10 \text{ mA}$	TCMT1103	CTR	100		200	%
I _C /I _F		TCMT1104	CTR	160		320	%
		TCMT1105	CTR	50		150	%
		TCMT1106	CTR	100		300	%
		TCMT1107	CTR	80		160	%
	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	TCMT1108	CTR	130		260	%
		TCMT1109	CTR	200		400	%
		TCMT4100	CTR	50		600	%
		TCMT4106	CTR	100		300	%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _d		3		μs
Rise time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _r		3		μs
Fall time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _f		4.7		μs
Storage time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _s		0		μs
Turn-on time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _{on}		6		μs
Turn-off time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _{off}		5		μs
Turn-on time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω , (see figure 2)	t _{on}		9		μs
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t _{off}		18		μs

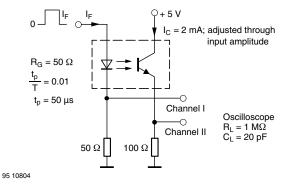


Fig. 1 - Test Circuit, Non-Saturated Operation

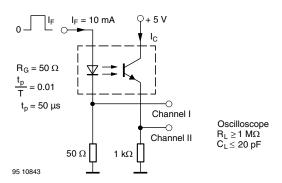


Fig. 2 - Test Circuit, Saturated Operation



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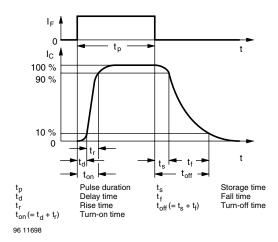


Fig. 3 - Switching Times

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification	IEC 68 part 1			40/110/21		
Comparative tracking index		CTI	175		399	
V _{IOTM}			6000			V
V _{IORM}			707			V
P _{SO}					265	mW
I _{SI}					130	mA
T _{SI}					150	°C
Creepage distance			5			mm
Clearance distance			5			mm
Insulation thickness, reinforced rated	per IEC60950 2.10.5.1		0.4			mm

Note

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

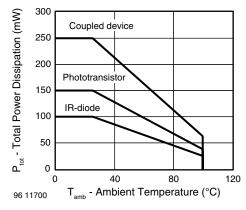


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

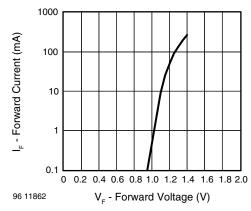
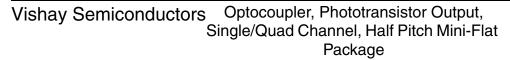


Fig. 5 - Forward Current vs. Forward Voltage





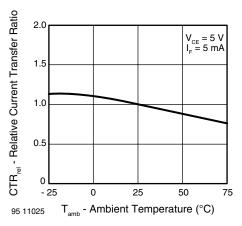


Fig. 6 - Relative Current Transfer Ratio vs.
Ambient Temperature

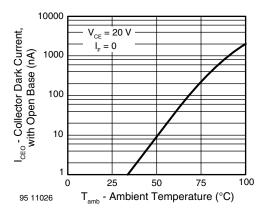


Fig. 7 - Collector Dark Current vs. Ambient Temperature

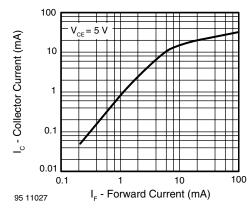


Fig. 8 - Collector Current vs. Forward Current

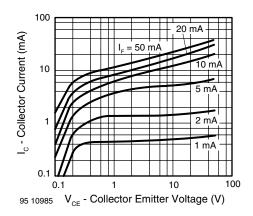


Fig. 9 - Collector Current vs. Collector Emitter Voltage

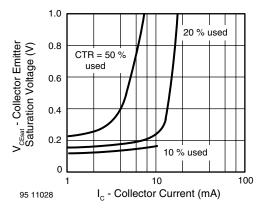


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

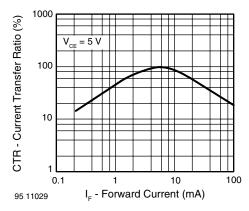


Fig. 11 - Current Transfer Ratio vs. Forward Current

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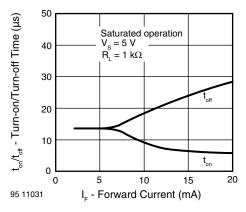


Fig. 12 - Turm-on/off Time vs. Forward Current

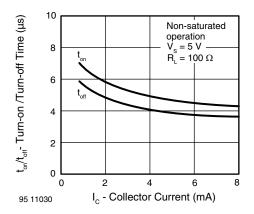
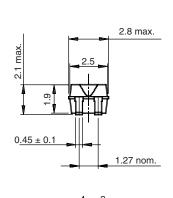
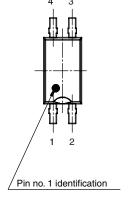
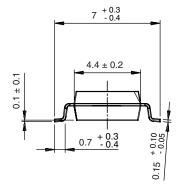


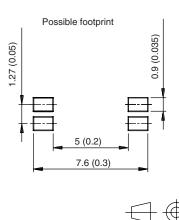
Fig. 13 - Turn-on/off Time vs. Collector Current

PACKAGE DIMENSIONS in inches (millimeters)





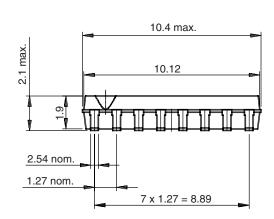


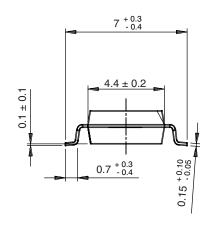


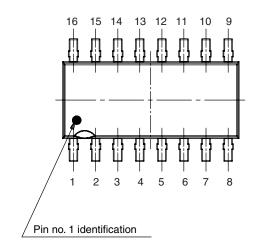
technical drawings according to DIN specifications

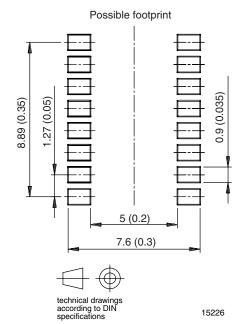


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Issue: 1; 04.04.00



Optocoupler, Phototransistor Output, Vishay Semiconductors Single/Quad Channel, Half Pitch Mini-Flat

Package

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

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